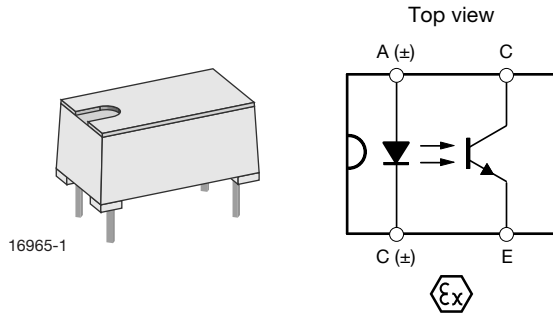


# Optocoupler, Phototransistor Output, ATEX Certified



## DESCRIPTION

The CNY65Exi consists of a phototransistor optically coupled to an infrared-emitting diode in a 4 pin plastic package. The components are mounted opposite one another, with a distance between input and output of > 3.0 mm; meeting the highest of safety requirements.

The CNY65Exi is ATEX certified for explosive atmospheres according to the European Guide line 94/9/EG.

## AGENCY APPROVALS

- ATEX  $\text{Ex}$ : PTB 03 ATEX 2033 U  
 EN 60079-0:2012  
 EN 60079-11:2012  
 EN 60079-26:2007

## FEATURES

- ATEX certificate: PTB 03 ATEX 2033 U  
[www.vishay.com/doc?85361](http://www.vishay.com/doc?85361)
- Suitable for intrinsic safe circuits for gas and dust
- Gas safety provision: II (1) G (EX ia) IIC
- Dust safety provision: II (1) D (EX ia) IIIC
- Conforms to EN60079-0:2012
- Qualified for continuously, longterm, or frequently dangerous explosive environments, zone 0
- Isolation voltage ( $V_{ISO}$ ) of 11 600  $V_{peak}$  for 1 minute
- Distance from emitter to detector through insulation  $\geq 3$  mm
- CTR from 50 % to 300 %
- Very low coupling capacity ( $C_K$ )
  - 0.3 pF superior noise immunity between input and output pins
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT

## APPLICATIONS

- Electronics used in potentially explosive gas and dust environments
  - Safety related process automation and instrumentation
  - Natural gas metering and flow measurement
  - Power and motor switching
  - Power supplies, metering, and data acquisition
  - Lighting and signaling
  - Petrol and grain transport and storage

| ORDERING INFORMATION  |                  |                   |
|---|------------------|-------------------|
| <div style="display: flex; justify-content: space-around; align-items: center;"> <div style="border: 1px solid black; padding: 2px 5px;">C</div> <div style="border: 1px solid black; padding: 2px 5px;">N</div> <div style="border: 1px solid black; padding: 2px 5px;">Y</div> <div style="border: 1px solid black; padding: 2px 5px;">6</div> <div style="border: 1px solid black; padding: 2px 5px;">5</div> <div style="border: 1px solid black; padding: 2px 5px;">X</div> <div style="border: 1px solid black; padding: 2px 5px;">E</div> <div style="border: 1px solid black; padding: 2px 5px;">x</div> <div style="border: 1px solid black; padding: 2px 5px;">i</div> </div> <div style="display: flex; justify-content: space-around; margin-top: 5px;"> <span>PART NUMBER</span> <span>CTR BIN</span> <span>PACKAGE OPTION</span> </div> |                  |                   |
| AGENCY CERTIFIED/PACKAGE  | CTR (%)          |                   |
| <b>ATEX</b>   | <b>50 to 300</b> | <b>100 to 200</b> |
| DIP-4, HV, high isolation distance  | CNY65Exi         | CNY65BExi         |



| ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |             |      |
|---|---|-------------------|-------------|------|
| PARAMETER   | TEST CONDITION                                  | SYMBOL            | VALUE       | UNIT |
| <b>INPUT</b>  |   |                   |             |      |
| Reverse voltage   |   | V <sub>R</sub>    | 5           | V    |
| Forward current   |   | I <sub>F</sub>    | 75          | mA   |
| Forward surge current   | t <sub>p</sub> ≤ 10 μs                          | I <sub>FSM</sub>  | 1.5         | A    |
| Power dissipation   |   | P <sub>diss</sub> | 120         | mW   |
| Junction temperature  |   | T <sub>j</sub>    | 100         | °C   |
| <b>OUTPUT</b>   |   |                   |             |      |
| Collector emitter voltage   |   | V <sub>CEO</sub>  | 32          | V    |
| Emitter collector voltage   |   | V <sub>ECO</sub>  | 7           | V    |
| Collector current   |   | I <sub>C</sub>    | 50          | mA   |
| Collector peak current  | t <sub>p</sub> /T = 0.5, t <sub>p</sub> ≤ 10 ms | I <sub>CM</sub>   | 100         | mA   |
| Power dissipation   |   | P <sub>diss</sub> | 130         | mW   |
| Junction temperature  |   | T <sub>j</sub>    | 100         | °C   |
| <b>COUPLER</b>  |   |                   |             |      |
| DC isolation test voltage   | t = 1 min                                       | V <sub>ISO</sub>  | 11.6        | kV   |
| Total power dissipation   |   | P <sub>tot</sub>  | 250         | mW   |
| Ambient temperature range   |   | T <sub>amb</sub>  | -55 to +85  | °C   |
| Storage temperature range   |   | T <sub>stg</sub>  | -55 to +100 | °C   |
| Soldering temperature   | 2 mm from case, t ≤ 10 s                        | T <sub>slid</sub> | 260         | °C   |

**Note**

- Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

| ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                                 |      |                  |      |      |
|---|--|---------------------------------|------|------------------|------|------|
| PARAMETER   | TEST CONDITION   | SYMBOL                          | MIN. | TYP.             | MAX. | UNIT |
| <b>INPUT</b>  |  |                                 |      |                  |      |      |
| Forward voltage   | I <sub>F</sub> = 50 mA   | V <sub>F</sub>                  |      | 1.25             | 1.6  | V    |
| <b>OUTPUT</b>   |  |                                 |      |                  |      |      |
| Collector emitter voltage   | I <sub>C</sub> = 1 mA  | V <sub>CEO</sub>                | 32   |                  |      | V    |
| Emitter collector voltage   | I <sub>E</sub> = 100 μA  | V <sub>ECO</sub>                | 7    |                  |      | V    |
| Collector dark current  | V <sub>CE</sub> = 20 V, I <sub>F</sub> = 0, E = 0                        | I <sub>CEO</sub>                |      |                  | 200  | nA   |
| <b>COUPLER</b>  |  |                                 |      |                  |      |      |
| DC isolation test voltage   | t = 1 min  | V <sub>ISO</sub> <sup>(1)</sup> | 11.6 |                  |      | kV   |
| Isolation resistance  | V <sub>IO</sub> = 1 kV,<br>40 % relative humidity                        | R <sub>IO</sub> <sup>(1)</sup>  |      | 10 <sup>12</sup> |      | Ω    |
| Collector saturation voltage  | I <sub>F</sub> = 10 mA, I <sub>C</sub> = 1 mA                            | V <sub>CEsat</sub>              |      |                  | 0.3  | V    |
| Cut-off frequency   | V <sub>CE</sub> = 5 V, I <sub>F</sub> = 10 mA,<br>R <sub>L</sub> = 100 Ω | f <sub>c</sub>                  | 110  |                  |      | kHz  |
| Coupling capacitance  | f = 1 MHz  | C <sub>k</sub>                  |      | 0.3              |      | pF   |

**Notes**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

<sup>(1)</sup> Related to standard climate 23/50 DIN 50014.

| CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |           |        |      |      |      |      |
|---|---|-----------|--------|------|------|------|------|
| PARAMETER   | TEST CONDITION                                | PART      | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| I <sub>C</sub> /I <sub>F</sub>  | V <sub>CE</sub> = 5 V, I <sub>F</sub> = 10 mA | CNY65Exi  | CTR    | 50   | 100  | 300  | %    |
|   |   | CNY65BExi | CTR    | 100  |      | 200  | %    |

| <b>SWITCHING CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |   |           |      |      |      |               |
|---|---|-----------|------|------|------|---------------|
| PARAMETER   | TEST CONDITION  | SYMBOL    | MIN. | TYP. | MAX. | UNIT          |
| Delay time  | $V_S = 5\text{ V}$ , $I_C = 5\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 1)       | $t_d$     |      | 2.6  |      | $\mu\text{s}$ |
| Rise time   | $V_S = 5\text{ V}$ , $I_C = 5\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 1)       | $t_r$     |      | 2.4  |      | $\mu\text{s}$ |
| Fall time   | $V_S = 5\text{ V}$ , $I_C = 5\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 1)       | $t_f$     |      | 2.4  |      | $\mu\text{s}$ |
| Storage time  | $V_S = 5\text{ V}$ , $I_C = 5\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 1)       | $t_s$     |      | 0.3  |      | $\mu\text{s}$ |
| Turn-on time  | $V_S = 5\text{ V}$ , $I_C = 5\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 1)       | $t_{on}$  |      | 5    |      | $\mu\text{s}$ |
| Turn-off time   | $V_S = 5\text{ V}$ , $I_C = 5\text{ mA}$ , $R_L = 100\ \Omega$ , (see figure 1)       | $t_{off}$ |      | 3    |      | $\mu\text{s}$ |
| Turn-on time  | $V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ , (see figure 2) | $t_{on}$  |      | 25   |      | $\mu\text{s}$ |
| Turn-off time   | $V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ , (see figure 2) | $t_{off}$ |      | 42.5 |      | $\mu\text{s}$ |

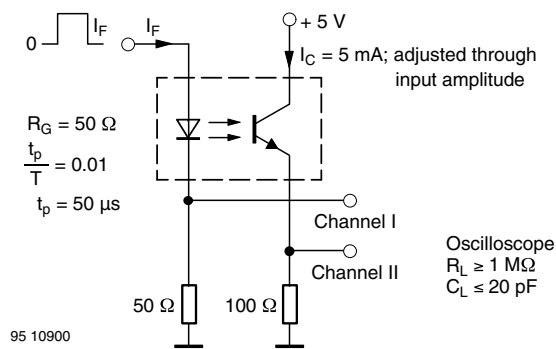


Fig. 1 - Test Circuit, Non-Saturated Operation

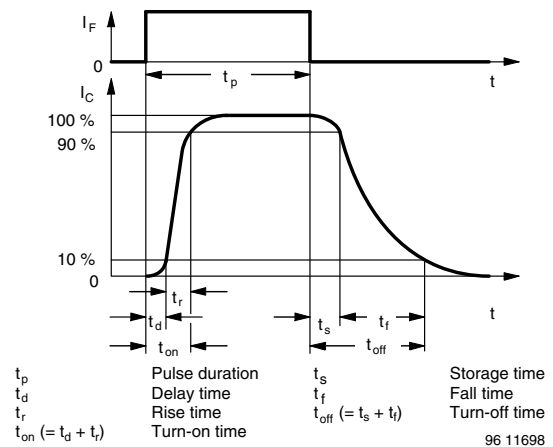


Fig. 3 - Switching Times

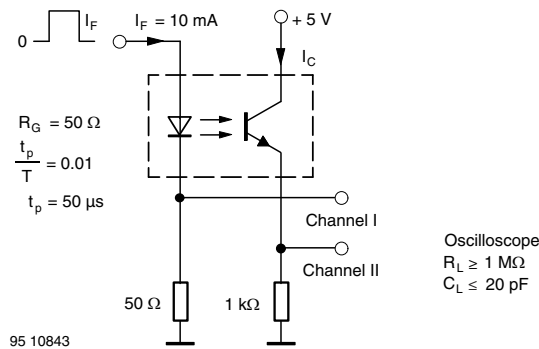


Fig. 2 - Test Circuit, Saturated Operation

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

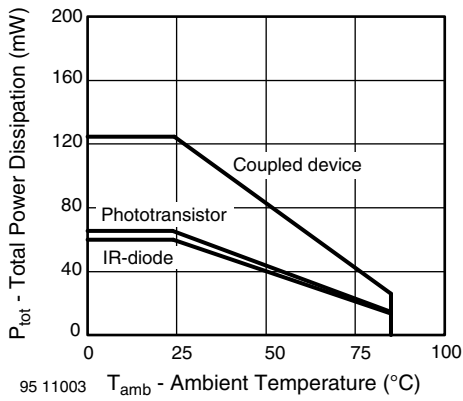


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

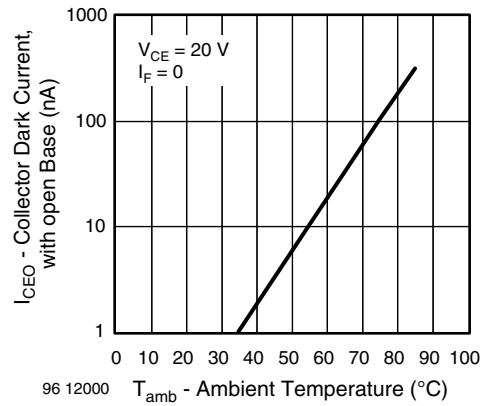
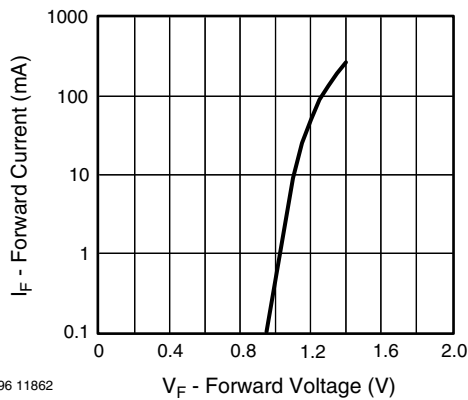
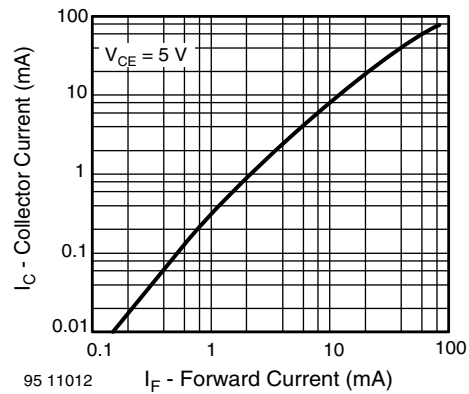


Fig. 7 - Collector Dark Current vs. Ambient Temperature



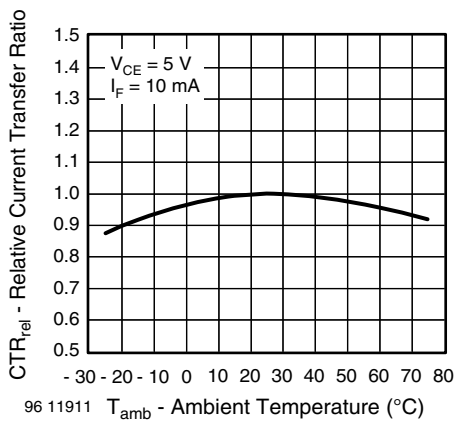
96 11862

Fig. 5 - Forward Current vs. Forward Voltage



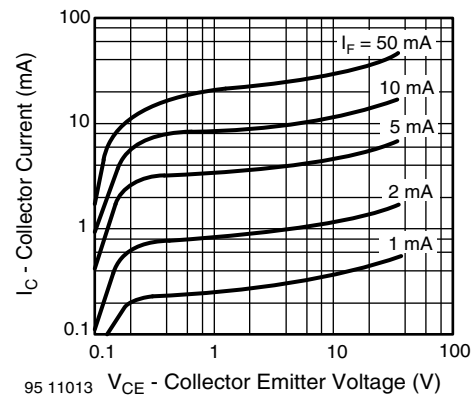
95 11012

Fig. 8 - Collector Current vs. Forward Current



96 11911

Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature



95 11013

Fig. 9 - Collector Current vs. Collector Emitter Voltage

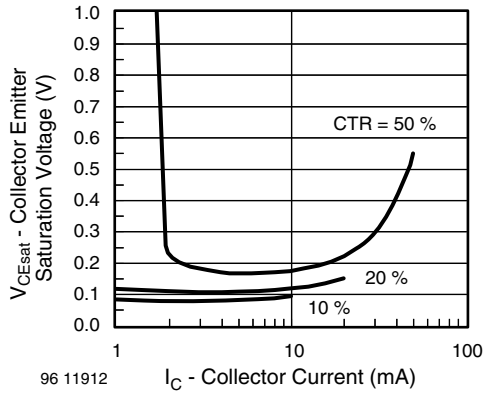


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

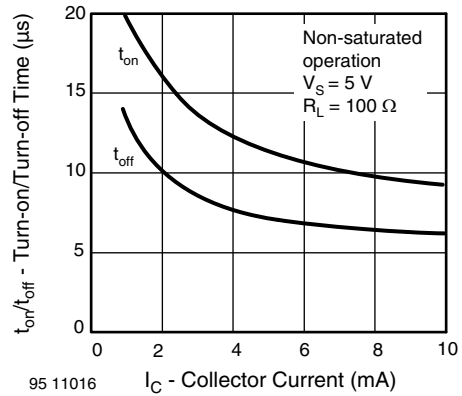


Fig. 13 - Turn-on/Turn-off Time vs. Collector Current

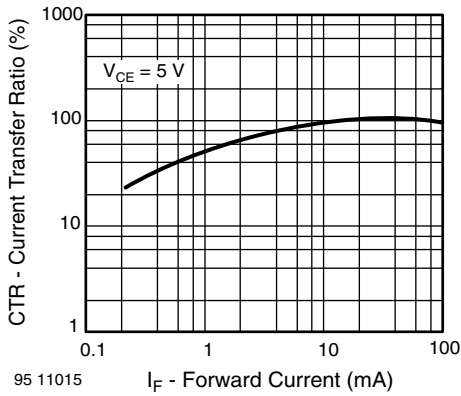


Fig. 11 - Current Transfer Ratio vs. Forward Current

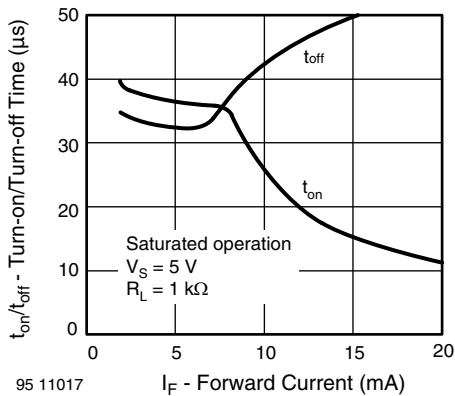
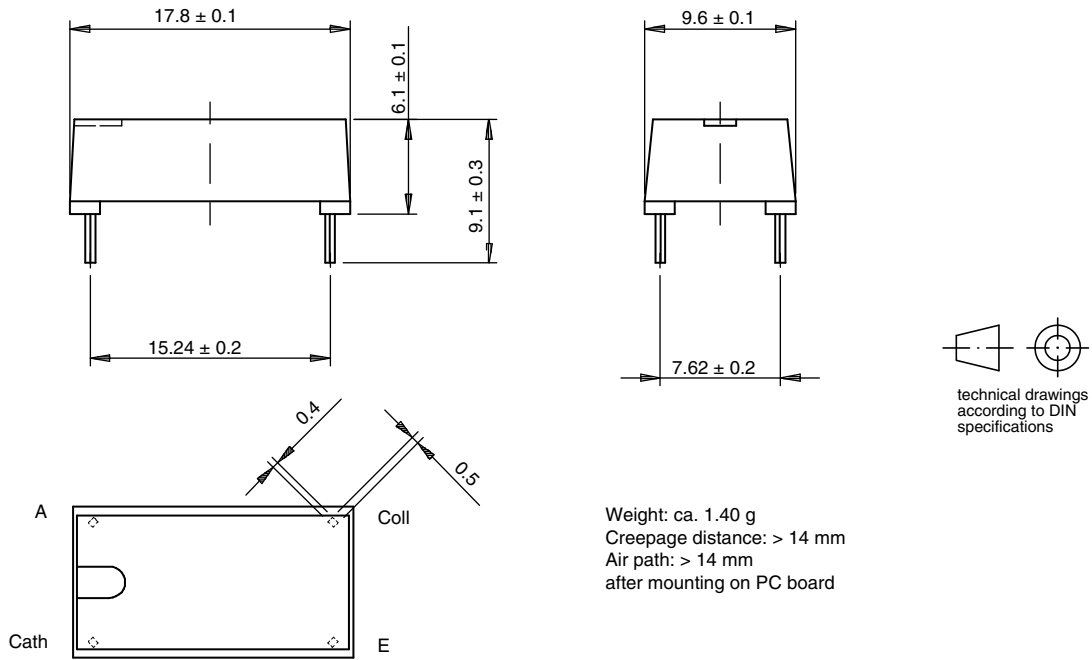


Fig. 12 - Turn-on/Turn-off Time vs. Forward Current

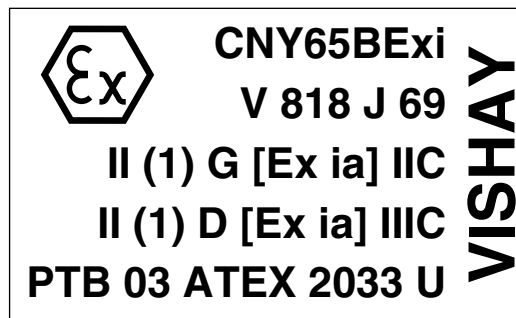
**PACKAGE DIMENSIONS** in millimeters



technical drawings according to DIN specifications

Drawing-No.: 6.544-5036.01-1  
 Issue: 2; 10.11.98  
 14763

**PACKAGE MARKING** (example of CNY65BExi)



**HANDLING AND STORAGE CONDITIONS**

ESD level: HBM class 2



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Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
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- Оперативные сроки поставки под заказ (от 5 рабочих дней);
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- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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## JONHON

«JONHON» (основан в 1970 г.)

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(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

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